NSN 5961-01-277-8611

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-277-8611 **Inclosure Material:** Plastic **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 collector to emitter voltage/static/base open all transistor and 40.0 collector to base voltage/static/emitter open all transistor **Current Rating Per Characteristic:** 75.00 milliamperes source cutoff current all transistor and 20.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 75.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0